

## 产品规格书

### Specifcation of products

产品名称: 整流单管模块

产品型号: MD55A-T03

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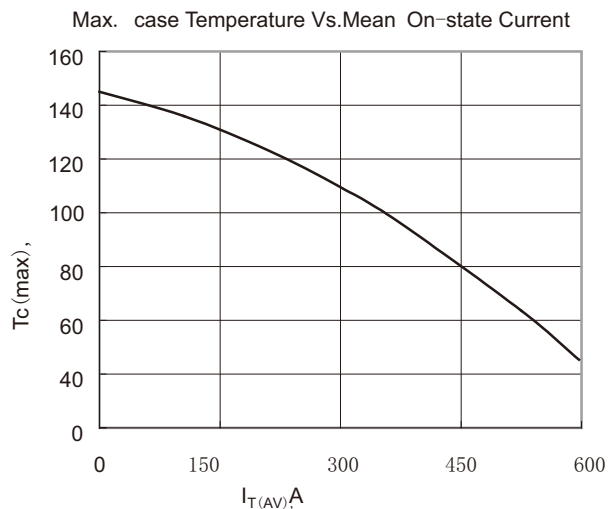
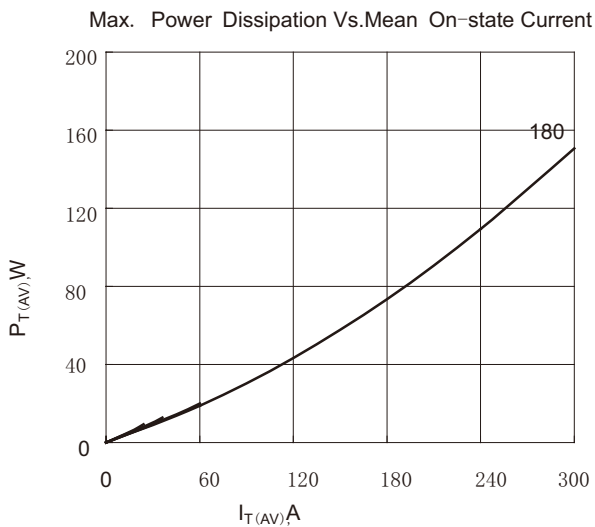
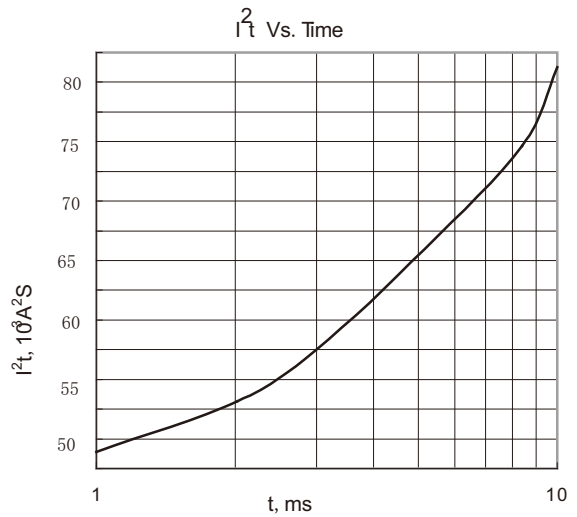
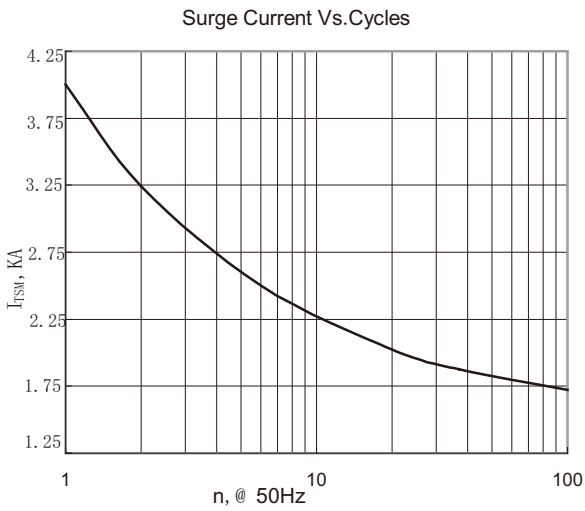
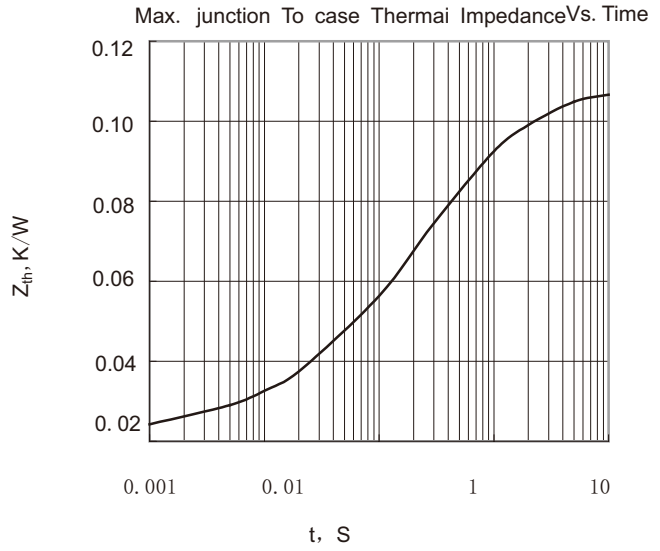
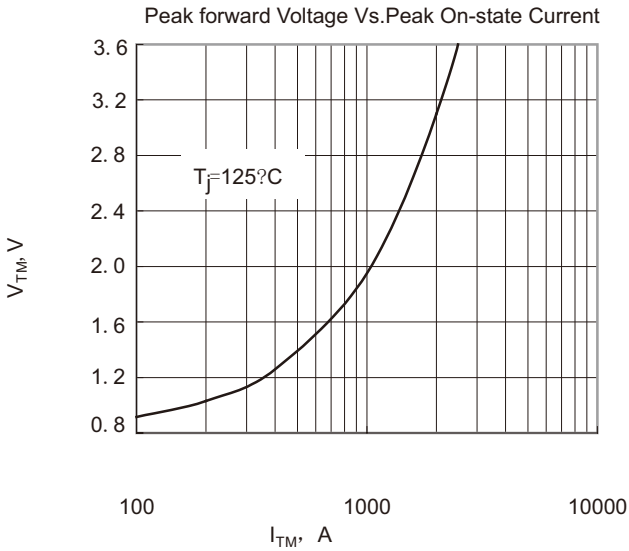
SYMBOL	CHARACTERISTIC	TEST CONDITIONS	T <sub>j</sub> (°C)	VALUE			UNIT
				Min	Type	Max	
I <sub>F(AV)</sub>	Mean for ward current	180° half sine wave 50Hz Single side cooled,T <sub>C</sub> =100°C	150			55	A
I <sub>F(RMS)</sub>	RMS for ward current	Single side cooled,T <sub>C</sub> =100°C	150			87	A
V <sub>RRM</sub>	Repetitive peak reverse voltage	V <sub>RRM</sub> tp=10ms V <sub>RSM</sub> = V <sub>DRM</sub> &V <sub>RRM</sub> +200V	150	600		2200	V
I <sub>RRM</sub>	Repetitive peak current	at V <sub>RRM</sub>	150			10	mA
I <sub>FSM</sub>	Surge for ward current	10ms half sine wave	150			12.5	KA
I <sup>2</sup> t I	<sup>2</sup> T for fusing coordination	V <sub>R</sub> =0.6V <sub>RRM</sub>					797
V <sub>FO</sub>	Threshold voltage		150			0.75	V
r <sub>F</sub>	Forward slop resistance						0.55
V <sub>FM</sub>	Peak for ward voltage	I <sub>FM</sub> =165A	25			1.10	V
R <sub>th(j-c)</sub>	Thermal resistance Junction to heatsink	At 180° sine Single side cooled				0.130	°C /W
V <sub>iso</sub>	Isolation voltage	50Hz, RM. S, t=1min, I <sub>iso</sub> : 1mA (max)		2500			V
F <sub>m</sub>	Terminal connection torque( M6)				5		N.m
	Mounting torque( M8)				7		N.m
T <sub>stg</sub>	Stored temperature			-40		150	°C
W <sub>t</sub>	Weight				95		g
Outline							

### OUTLINE DR AWING & CIRCUIT DIAGRAM

# MD



## Rating and Characteristic



## Outside Dimension

